

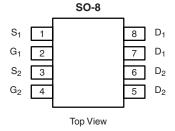
# AP9938GEM-HF-VB Datasheet **Dual N-Channel 20-V (D-S) MOSFET**

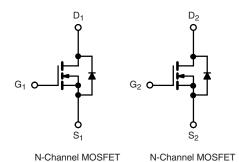
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
20	0.019 at $V_{GS} = 4.5 \text{ V}$	7.1		
	0.026 at V <sub>GS</sub> = 2.5 V	6.0		

#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- 100 % R<sub>g</sub> Tested Compliant to RoHS Directive 2002/95/EC







ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted					
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	$V_{DS}$	20	V		
Gate-Source Voltage	$V_{GS}$	± 12	V		

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		$V_{DS}$	20	V	
Gate-Source Voltage		$V_{GS}$	± 12	ď	
Continuous Drain Current (T, J = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	. I <sub>D</sub>	7.1	A	
Continuous Diam Current (1j = 150 °C)	T <sub>A</sub> = 70 °C		5.7		
Pulsed Drain Current (10 μs Pulse Width)		I <sub>DM</sub>	40	^	
Continuous Source Current (Diode Conduction) <sup>a</sup>	I <sub>S</sub>	1.7			
Marrian Parray Disabation	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	2	w	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	טי	1.3	] "	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Maximum Junction-to-Ambient <sup>a</sup>	R <sub>thJA</sub>	62.5	°C/W		

a. Surface Mounted on FR4 board,  $t \le 10$  s.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	•			•		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6		1.5	V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA
Zava Cata Valta na Duain Comunit		V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V		1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	20			Α
		$V_{GS} = 4.5 \text{ V}, I_D = 7.1 \text{ A}$	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 7.1 A			Ω
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 6.0 A		0.026		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 7.1 A		27		S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = 1.7 A, V <sub>GS</sub> = 0 V			1.2	٧
Dynamic <sup>b</sup>				•		
Total Gate Charge	Qg			9.5		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 7.1 \text{ A}$		1.5		nC
Gate-Drain Charge	$Q_{gd}$			2.5		
Gate Resistance	$R_g$	f = 1 MHz		1.6	2.7	Ω
Turn-On Delay Time	t <sub>d(on)</sub>			10		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 10 $\Omega$		15		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong 1$ A, $V_{GEN}=4.5$ V, $R_g=10\Omega$		38		ns
Fall Time	t <sub>f</sub>			25		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.7 A, dI/dt = 100 A/μs		26		

#### Notes:

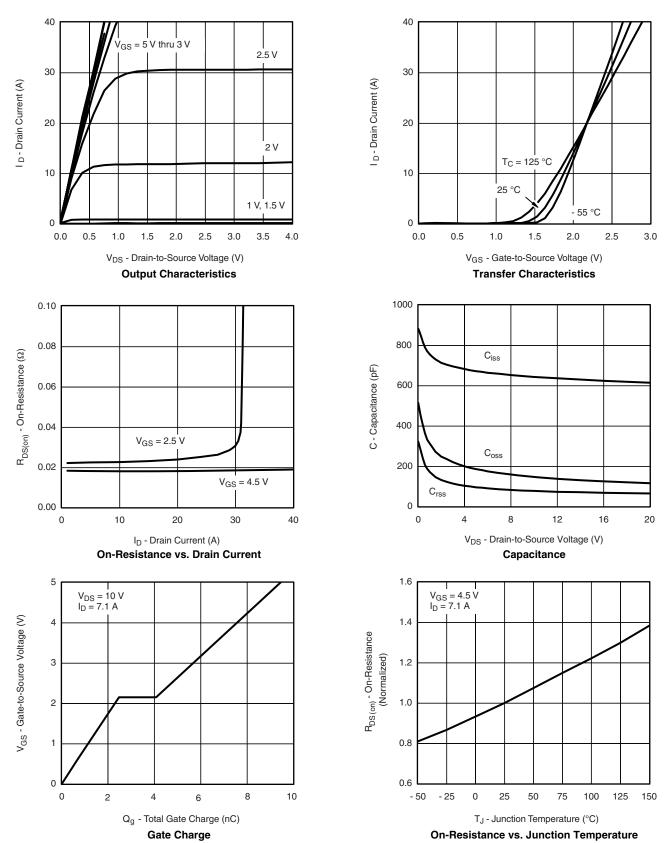
- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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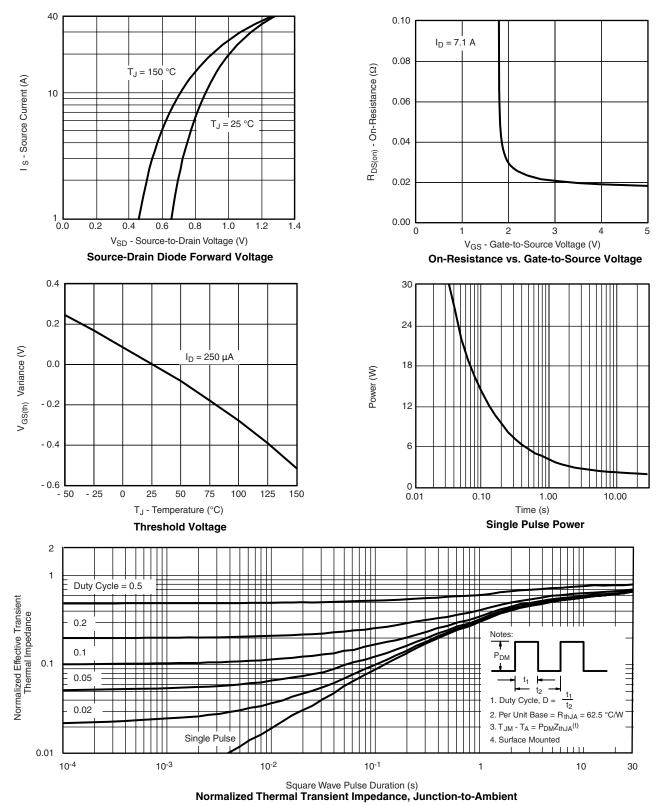
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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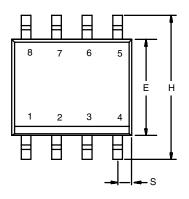


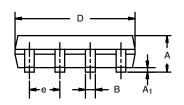
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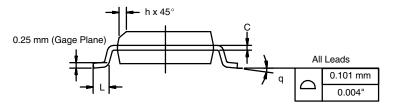




SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIMETERS INCHES			HES	
DIM	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A <sub>1</sub>	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
Е	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06					

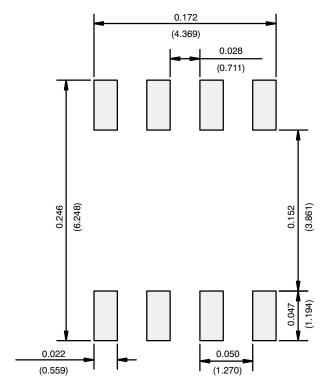
ECN: C-06527-Rev. I, 11-Sep-06

DWG: 5498

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### **RECOMMENDED MINIMUM PADS FOR SO-8**



Recommended Minimum Pads Dimensions in Inches/(mm)

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